

N-channel 30 V, 0.82 mΩ, 300 A logic level MOSFET in LFPAK56 using NextPowerS3 technology 12 November 2019

Product data sheet

1. General description

Logic level gate drive N-channel enhancement mode MOSFET in LFPAK56 package optimized for low R_{DSon}. Low I_{DSS} leakage even when hot, high efficiency and high current rated to 300 A, optimized for DC load switch and hot-swap applications.

2. Features and benefits

- 100% avalanche tested at $I_{(AS)}$ = 190 A
- Optimized for low R_{DSon}
- Low leakage < 1 µA at 25 °C
- · Low spiking and ringing for low EMI designs
- Optimized for 4.5 V gate drive
- Copper-clip for low parasitic inductance and resistance
- High reliability LFPAK package, qualified to 175 °C
- Wave solderable; exposed leads for optimal solder coverage and visual solder inspection

3. Applications

- Hot swap
- e-fuse
- Power OR-ing
- DC switch / Load switch
- Battery protection
- Brushed and BLDC (brushless) motor control
- Synchronous rectification in AC-DC and DC-DC applications

4. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	30	V
ID	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	-	300	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	268	W
Tj	junction temperature			-55	-	175	°C
Static chara	acteristics						_
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 10		-	0.66	0.82	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _j = 25 °C; Fig. 10		-	0.86	1.1	mΩ
Dynamic cł	naracteristics						
Q _{GD}	gate-drain charge	I_D = 25 A; V_{DS} = 15 V; V_{GS} = 4.5 V;		2.9	16	32	nC
Q _{G(tot)}	total gate charge	Fig. 12; Fig. 13		21	46	76	nC

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Source-drain diode							
S		$I_{S} = 25 \text{ A}; \text{ d}I_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V}; \\ \text{V}_{DS} = 15 \text{ V}; \text{ Fig. 16}$		-	0.96	-	

[1] 300A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

5. Pinning information

Table 2.	Fable 2. Pinning information										
Pin	Symbol	Description	Simplified outline	Graphic symbol							
1	S	source	mb	D							
2	S	source									
3	S	source		G-(F+A)							
4	G	gate		mbb076 S							
mb	D mounting base; connected to drain	LFPAK56; Power- SO8 (SOT669)									

6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
PSMNR70-30YLH	LFPAK56; Power-SO8	plastic, single-ended surface-mounted package; 4 terminals	SOT669				

7. Marking

Table 4. Marking codes	
Type number	Marking code
PSMNR70-30YLH	H7030L

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

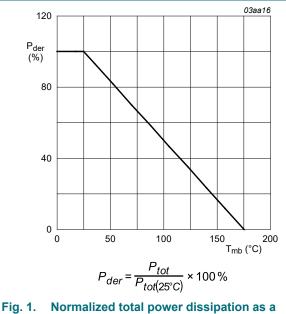
Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	30	V
V _{DGR}	drain-gate voltage	$25 \text{ °C} \le \text{T}_{j} \le 175 \text{ °C}; \text{R}_{\text{GS}} = 20 \text{ k}\Omega$		-	30	V
V _{GS}	gate-source voltage			-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	268	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	300	А
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	281	А
I _{DM}	peak drain current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$; Fig. 3		-	1589	А
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C

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12 November 2019

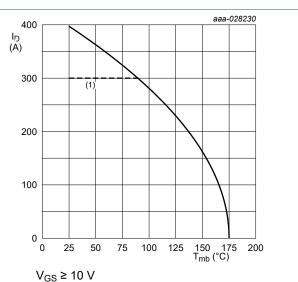
Symbol	Parameter	Conditions		Min	Max	Unit
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-drain	n diode					
I _S	source current	T _{mb} = 25 °C		-	268	А
I _{SM}	peak source current	pulsed; t _p ≤ 10 µs; T _{mb} = 25 °C		-	1589	А
Avalanche r	uggedness					
E _{DS(AL)S}		$ \begin{split} &I_{D} = 25 \text{ A}; V_{sup} \leq \ 30 \text{ V}; R_{GS} = 50 \ \Omega; \\ &V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \ ^{\circ}\text{C}; unclamped; \\ &t_{p} = 4.9 \ ms \end{split} $	[2]	-	2.4	J
I _{AS}	non-repetitive avalanche current		[2]	-	190	A

[1] 300A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

[2] Protected by 100% test

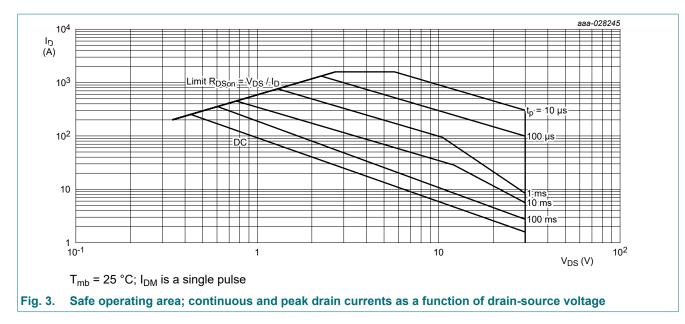


function of mounting base temperature



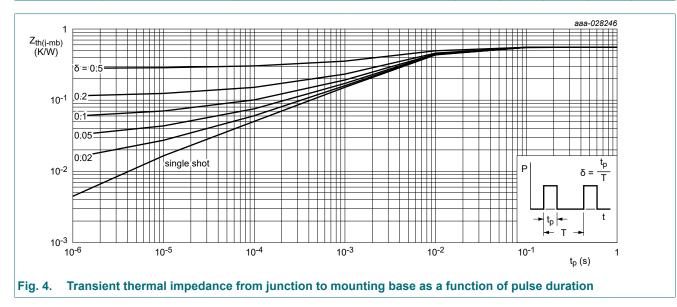
(1) 300A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

Fig. 2. Continuous drain current as a function of mounting base temperature

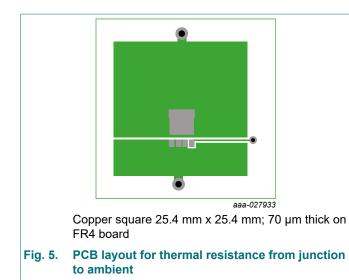


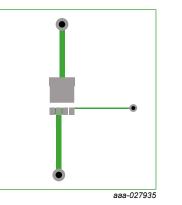
9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. <u>4</u>	-	0.48	0.56	K/W
R _{th(j-a)}	thermal resistance from	Fig. 5	-	42	-	K/W
junction to ambient	Fig. 6	-	85	-	K/W	



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70 µm thick copper on FR4 board

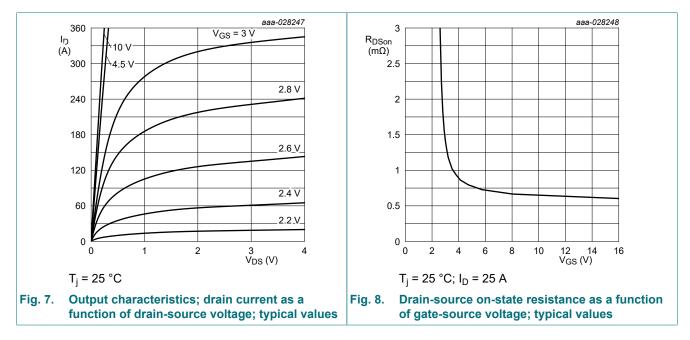
Fig. 6. PCB layout with minimum footprint for thermal resistance from junction to ambient

10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static charac	teristics					
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	30	-	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	27	-	-	V
V _{GS(th)}	gate-source threshold voltage	$I_D = 2 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	1.2	1.5	2.2	V
$\Delta V_{GS(th)} / \Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T _j ≤ 150 °C	-	-4.4	-	mV/K
I _{DSS}	drain leakage current	V _{DS} = 24 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA
		V _{DS} = 24 V; V _{GS} = 0 V; T _j = 125 °C	-	6.4	-	μA
I _{GSS}	gate leakage current	V _{GS} = 16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
		V _{GS} = -16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 10	-	0.66	0.82	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 150 °C; Fig. 11	-	-	1.5	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _j = 25 °C; Fig. 10	-	0.86	1.1	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _j = 150 °C; Fig. 11	-	-	2	mΩ
R _G	gate resistance	f = 1 MHz; T _j = 25 °C	0.5	1.3	3.3	Ω
Dynamic cha	racteristics					
Q _{G(tot)}	total gate charge	I_D = 25 A; V_{DS} = 15 V; V_{GS} = 4.5 V; Fig. 12; Fig. 13	21	46	76	nC
		I_D = 25 A; V_{DS} = 15 V; V_{GS} = 10 V; Fig. 12; Fig. 13	43	95	157	nC
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V	-	50	-	nC

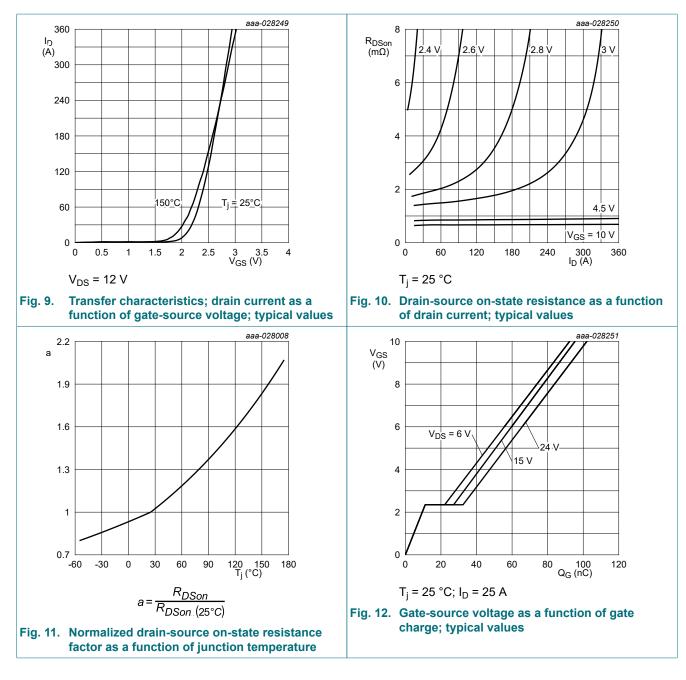
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Q _{GS}	gate-source charge	I _D = 25 A; V _{DS} = 15 V; V _{GS} = 4.5 V;		3	11	21	nC
Q _{GS(th)}	pre-threshold gate- source charge	Fig. 12; Fig. 13		2.2	8	15	nC
Q _{GS(th-pl)}	post-threshold gate- source charge	-		0.86	3.2	6.1	nC
Q _{GD}	gate-drain charge			2.9	16	32	nC
V _{GS(pl)}	gate-source plateau voltage	I _D = 25 A; V _{DS} = 15 V; <u>Fig. 12; Fig. 13</u>		-	2.3	-	V
C _{iss}	input capacitance	V _{DS} = 15 V; V _{GS} = 0 V; f = 1 MHz;		3284	5473	8210	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 14</u>		1702	2836	4254	pF
C _{rss}	reverse transfer capacitance	-		129	478	1147	pF
t _{d(on)}	turn-on delay time	V_{DS} = 15 V; R_{L} = 0.6 Ω ; V_{GS} = 4.5 V;		-	28	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega$		-	51	-	ns
t _{d(off)}	turn-off delay time			-	61	-	ns
t _f	fall time	-		-	45	-	ns
Q _{oss}	output charge	V _{GS} = 0 V; V _{DS} = 15 V; f = 1 MHz; T _j = 25 °C		-	62	-	nC
Source-dra	in diode	1					
V _{SD}	source-drain voltage	I _S = 25 A; V _{GS} = 0 V; T _j = 25 °C; <u>Fig. 15</u>		-	0.75	1	V
t _{rr}	reverse recovery time	$I_{S} = 25 \text{ A}; \text{ dI}_{S}/\text{dt} = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$		-	46	-	ns
Q _r	recovered charge	V _{DS} = 15 V; <u>Fig. 16</u>	[1]	-	50	-	nC
t _a	reverse recovery rise time	-		-	23.4	-	ns
t _b	reverse recovery fall time			-	22.5	-	ns
S	softness factor			-	0.96	-	

[1] includes capacitive recovery

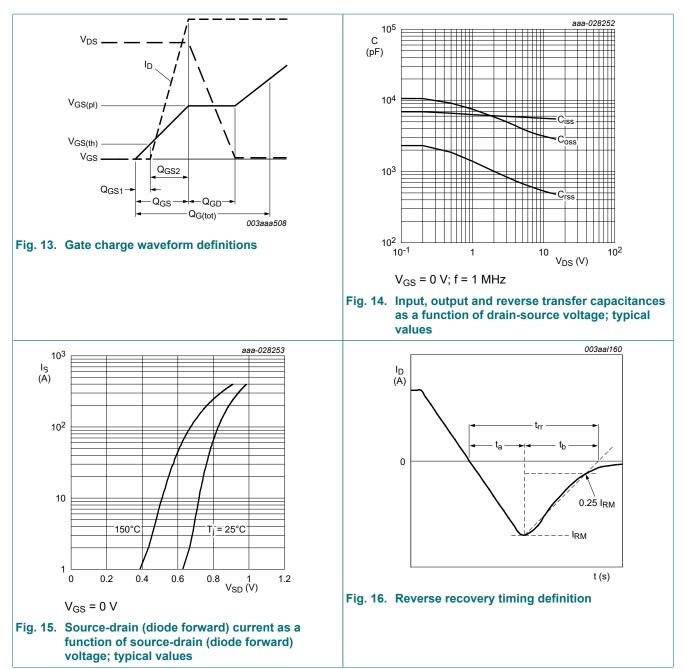


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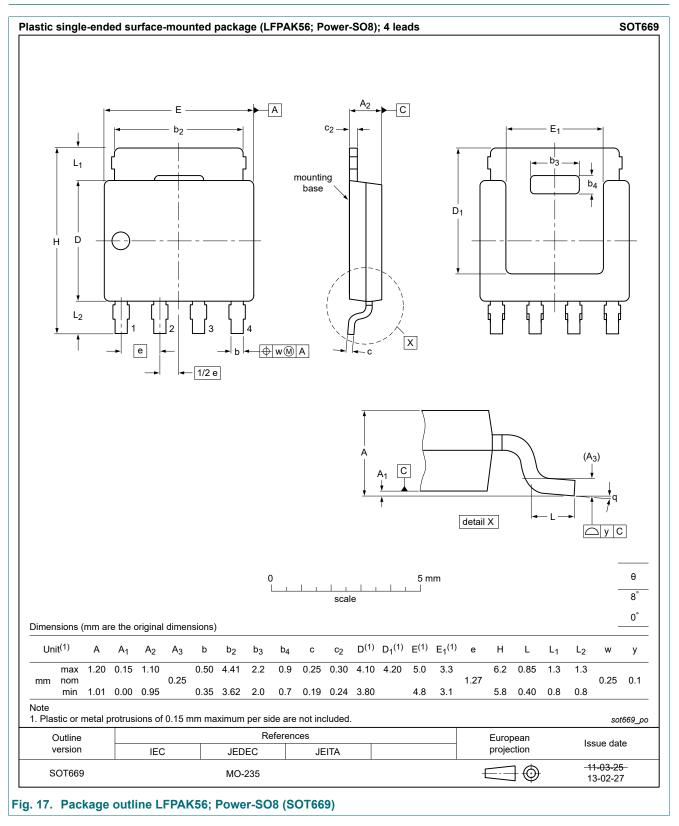


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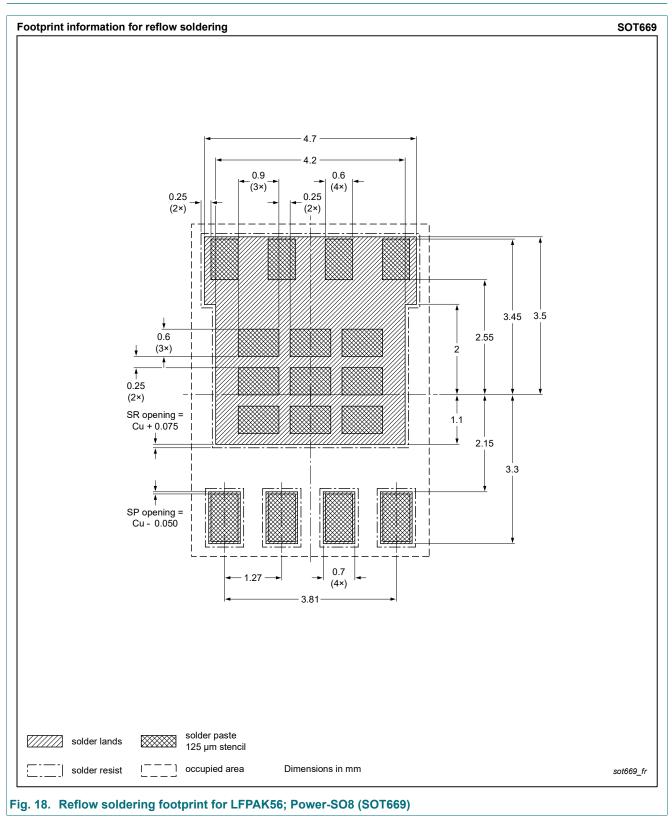


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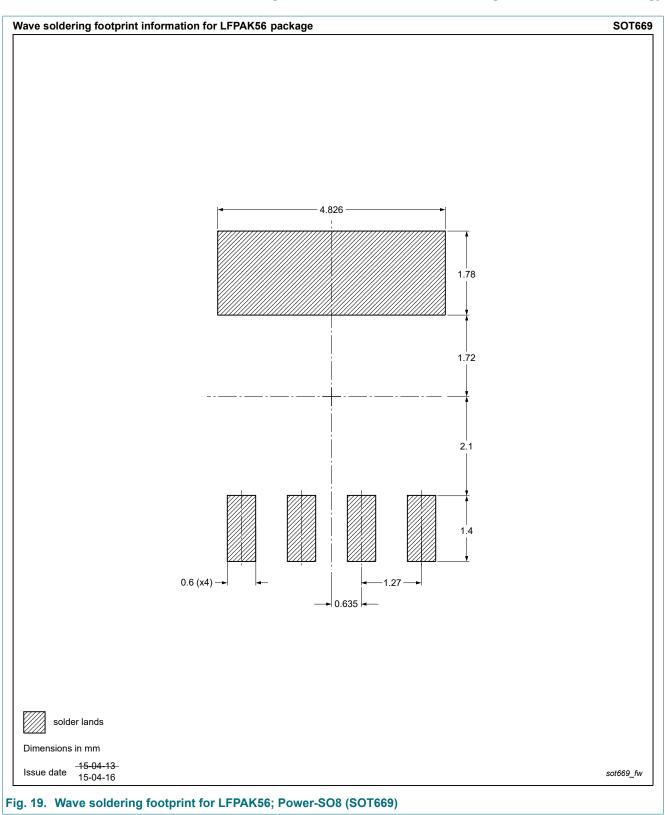
11. Package outline



12. Soldering



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13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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